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Attorney Docket # 5367-146PUS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re National Phase PCT Application of
Dominik EISERT et al.
International Appln. No.: PCT/DE2003/002071
International Filing Date: June 20, 2003
For: GaN-Based Radiation-Emitting Thin-Layered
Semiconductor Component

PRELIMINARY AMENDMENT

Mail Stop **PCT**
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

S I R:

Prior to examination of the above-identified application please amend the application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 13 of this paper.

Amendments to the Abstract are on page 22 of this paper

Amendments to the Drawings begin on page 23 of this paper and include an attached replacement sheet.

Remarks/Arguments begin on page 24 of this paper.